

RoHS Compliant Product  
A Suffix of "-C" specifies halogen & lead-free

## DESCRIPTION

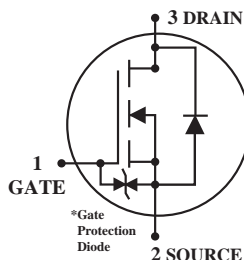
- Low on-resistance
- Fast switching speed
- Easily designed drive circuits
- Easy to parallel

## FEATURES

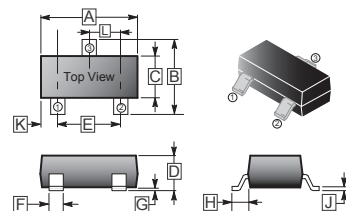
- Simple drive requirement
- Small package outline

## MARKING

KN



## SOT-323



REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	1.80	2.20	G	0.100	REF.
B	1.80	2.45	H	0.525	REF.
C	1.15	1.35	J	0.08	0.25
D	0.80	1.10	K	-	-
E	1.20	1.40	L	0.650	TYP.
F	0.20	0.40			

## MAXIMUM RATINGS (T<sub>A</sub> = 25°C unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Drain – Source Voltage	V <sub>DS</sub>	30	V
Gate – Source Voltage	V <sub>GS</sub>	±20	V
Continuous Drain Current	I <sub>D</sub>	100	mA
Power Dissipation <sup>1</sup>	P <sub>D</sub>	200	mW
Maximum Junction to Ambient	R <sub>θJA</sub>	625	°C / W
Operating Junction & Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	150, -55~150	°C

## ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise specified)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
<b>Off Characteristics</b>						
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	30	-	-	V	V <sub>GS</sub> =0, I <sub>D</sub> =10μA
Gate-Threshold Voltage	V <sub>GS(TH)</sub>	0.8	-	1.5	V	V <sub>DS</sub> =3V, I <sub>D</sub> =100μA
Gate-Source Leakage Current	I <sub>GSS</sub>	-	-	±500	nA	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0
Drain-Source Leakage Current	I <sub>DSS</sub>	-	-	0.2	μA	V <sub>DS</sub> =30V, V <sub>GS</sub> =0
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	-	-	8	Ω	V <sub>GS</sub> =4V, I <sub>D</sub> =10mA
		-	-	13		V <sub>GS</sub> =2.5V, I <sub>D</sub> =1mA
Forward Transconductance	g <sub>FS</sub>	20	-	-	ms	V <sub>DS</sub> =3V, I <sub>D</sub> =10mA
<b>Dynamic Characteristics<sup>1</sup></b>						
Input Capacitance	C <sub>ISS</sub>	-	13	-	pF	V <sub>DS</sub> =5V
Output Capacitance	C <sub>OSS</sub>	-	9	-		V <sub>GS</sub> =0
Reverse Transfer Capacitance	C <sub>RSS</sub>	-	4	-		f=1MHz
<b>Switching Characteristics<sup>1</sup></b>						
Turn-on Delay Time	T <sub>d(ON)</sub>	-	15	-	ns	V <sub>GS</sub> =5V, V <sub>DD</sub> =5V
Rise Time	T <sub>R</sub>	-	35	-		I <sub>D</sub> =10mA
Turn-off Delay Time	T <sub>d(OFF)</sub>	-	80	-		R <sub>L</sub> =500Ω
Fall Time	T <sub>F</sub>	-	80	-		R <sub>G</sub> =10Ω

Note:

1. These parameters have no way to verify.

**CHARACTERISTIC CURVES**

